

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

TK16J60W5

• FEATURES Low drain-source on-resistance: Ros(on) ≤0.23Ω. · Enhancement mode: Vth =3.0 to 4.5V (VDs = 10 V, ID=0.79mA) 100% avalanche tested pin 1.Gate Minimum Lot-to-Lot variations for robust device 2.Drain performance and reliable operation 3. Source 1 2 3 TO-3PN package DESCRITION Switching Voltage Regulators C S • ABSOLUTE MAXIMUM RATINGS(Ta=25°C) VALUE SYMBOL PARAMETER UNIT Ó VDSS Drain-Source Voltage 600 V V_{GS} Gate-Source Voltage ± 30 V I_{D} **Drain Current-Continuous** 15.8 А R mm **I**DM Drain Current-Single Pulsed 63.2 А DIM MIN MAX 19.60 20.30 А 15.50 В 15.70 P_{D} Total Dissipation @Tc=25℃ 130 W 4.70 C 4.90 0.90 D 1,10 E 1.90 2.10 Max. Operating Junction Temperature 150 °C Tj F 3.40 3,60 2.90 G 3.20 Н 3.20 3 40 Storage Temperature °C Tstg -55~150 .1 0.595 0.605 κ 19.80 1.90 N 10.89 THERMAL CHARACTERISTICS Q 4.90 R 3.35 3.45 SYMBOL MAX UNIT PARAMETER 1,995 2.100 s 5.90 6.20 U °C/W Rth(ch-c) Channel-to-case thermal resistance 0.962 9.90 10.10 Y

1

isc website: www.iscsemi.cn



isc N-Channel MOSFET Transistor

TK16J60W5

ELECTRICAL CHARACTERISTICS

$T_{\rm C}\text{=}25^\circ\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =10mA	600			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =10V; I _D =0.79mA	3.0		4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =7.9A			0.23	Ω
lgss	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} = 0V			±1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =600V; V _{GS} = 0V			100	μA
V _{SDF}	Diode forward voltage	I _{DR} =15.8A, V _{GS} = 0 V			1.7	V

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications. ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.